



# **Reliability Test Report**

Product Name: CA-IS372XCX

Report Version: V1.2

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### 1. Overview

Reliability testing of microelectronic products is a risk mitigation process designed to ensure the service life of device in customer applications. Semiconductor wafer manufacturing process and package-level reliability can be assessed in a variety of ways and may include accelerated environmental test conditions. Chipanalog evaluates manufacturability of the device to verify a robust silicon and assembly flow to ensure continuity of supply to customers. Chipanalog qualifies new devices, significant changes, and product families based on JEDEC JESD47. CA-IS372XCX series chips are packaged with the same wafer. The differences between part numbers are the package and bonding diagram. The data shown is representative of the material sets, processes, and manufacturing sites used by the device family.

### 2. Part Number List

Package Type	Part Number
CA-IS3720CHS/CA-IS3720CLS/CA-IS3721CHS/CA-IS3721CLS/	
SOIC8-NB(S)	CA-IS3722CHS/ CA-IS3722CLS
SOIC8-WB(G)	CA-IS3722CHG
SOIC16-WB(W) CA-IS3722CHW/ CA-IS3721CHW/ CA-IS3720CHW/ CA-IS3720CLW	

Note: JEDEC specification is designed to also qualify a family of similar components utilizing the same fabrication process, design rules, and similar circuits. The family qualification may also be applied to a package family where the construction is the same and only the size and number of leads differs.

### 3. Product Information

### 3.1. Wafer Information

Wafer	HUANGLONG
Fab Process	18BCD

### 3.2. Package Information

Assembly site	SiMAT	SiMAT	SiMAT
FT site	SiMAT	SiMAT	SiMAT
Package	SOIC8-NB	SOIC8-WB	SOIC16-WB
Lead frame	Cu	Cu	Cu
Bond wire	20um AuPdCu	20um AuPdCu	20um AuPdCu
MSL level	MSL3	MSL3	MSL3



# 4. Reliability Qualification Plan

# 4.1. Device Qualification Test Requirements

Stress	Ref.	Abbv.	Conditions	Duration /Accept	
Electrical Parameter	JESD86	ED	Per Datasheet	Par Datashoot	
Assessment	JE3D00	בט	Fei Datastieet	Per Datasheet	
High Temperature	JESD22-A108,	LITOI	T <sub>J</sub> ≥ 125°C	1000 brs /0 Fail	
Operating Life	JESD85	HTOL	V <sub>CC</sub> ≥V <sub>CC</sub> max	1000 hrs/0 Fail	
Human Body Model	IC 001	ESD-	T. 25°C	Classification	
ESD	JS-001	HBM	T <sub>A</sub> = 25°C	Classification	
Charged Device	IC 002	ESD-	T 25°C	Classification	
Model ESD	JS-002	CDM	T <sub>A</sub> = 25°C	Classification	
Latch-Up	JESD78	LU	Class I or Class II	Classification	

## 4.2. Nonhermetic Package Qualification Test Requirements

Stress	Ref.	Abbv.	Conditions	Duration /Accept
MSL Preconditioning	JESD22-A113	PC	Per appropriate MSL level per J-STD-020	Electrical Test (optional)
High Temperature Storage	JESD22-A103 & A113	HTSL	150°C, 1000 hrs	1000 hrs/0 Fail
Temperature Humidity Bias	JESD22-A101	ТНВ	85°C, 85% RH, Vcc max	1000 hrs/0 Fail
Highly Accelerated Temperature and Humidity Stress	JESD22-A110	HAST	130°C/110°C, 85% RH, 33.3/17.7 psia, V <sub>cc1</sub> = 5.5V, V <sub>cc2</sub> = 5.5V	96/264 hrs/0 Fail
Temperature Cycling	JESD22-A104	TC	-65°C to 150°C	500 cycles/0 Fail
Unbiased Temperature/Humidity	JESD22-A102	AC	121°C, 100% RH, 29.7psia	96 hrs/0 Fail
Unbiased Temperature/Humidity	JESD22-A118	UHAST	130°C/110°C, 85% RH, 33.3/17.7 psia	96/264 hrs/0 Fail
Bond Pull Strength	JESD22-B120	BPS	Characterization, Pre Encapsulation	Ppk≥1.66 or Cpk≥1.33
Bond Shear	JESD22-B116	BS	Characterization, Pre Encapsulation	Ppk≥1.66 or Cpk≥1.33
Solderability	M2003 JESD22-B102	SD	Characterization	95% coverage

Note: Either HAST or THB may be chosen. If THB or HAST is run, then UHAST need not be run. Autoclave is not recommended as a qualification test; Unbiased or biased HAST is the recommended stress and is required for organic substrates instead of Autoclave.



# 5. Reliability Test Results

# **5.1. Device Reliability Test Results**

Stress	Condition	Duration	Sample Size	Result	Classification
ED	Per Datasheet	/	10*3 lot	Pass	/
HTOL	TA = $125$ °C, V <sub>cc1</sub> = $5.5$ V, V <sub>cc2</sub> = $5.5$ V	1000 hrs	77*3 lot	Pass	/
ESD-HBM	$V_{cc1} = 5.5V$ , $V_{cc2} = 5.5V$	/	3*1 lot	Pass	Class 3B
ESD-CDM	T <sub>A</sub> = 25°C	/	3*1 lot	Pass	Class C3
LU	T <sub>A</sub> = 25°C	/	3*1 lot	Pass	Class I.A

Note: 1 lot HTOL test data comes from qualification of CA-IS3722CHS, another 2 lot HTOL test data comes from qualification of CA-IS3722LG.

## **5.2. Package Reliability Test Results**

	Package <sup>-</sup>	Type: SOIC8-NB		
Stress	Condition	Duration	Sample size	Results
PC	MSL 3	/	231*3 lot	Pass
HTSL	T <sub>A</sub> = 150°C	1000 hrs	77*3 lot	Pass
HAST	130°C, 85% RH, 33.3psia, V <sub>cc1</sub> = 5.5V, V <sub>cc2</sub> = 5.5V	96 hrs	77*3 lot	Pass
TC	-65°C to 150°C	500 cycles	77*3 lot	Pass
UHAST	130°C, 85% RH, 33.3psia	96 hrs	77*3 lot	Pass
BPS	JESD22-B120	/	30 bonds/5 ea.	Pass
BS	JESD22-B116	/	30 bonds/5 ea.	Pass
SD	Steam aging, 245°C dipping	5s	22 leads*3 lot	Pass
	Package 1	Type: SOIC8-WB		
Stress	Condition	Duration	Sample size	Results
PC	MSL 3	/	231*3 lot	Pass
HTSL	T <sub>A</sub> = 150°C	1000 hrs	77*3 lot	Pass
HAST	130°C, 85% RH, 33.3psia, V <sub>cc1</sub> = 5.5V, V <sub>cc2</sub> = 5.5V	96 hrs	77*3 lot	Pass
TC	-65°C to 150°C	500 cycles	77*3 lot	Pass
UHAST	130°C, 85% RH, 33.3psia	96 hrs	77*3 lot	Pass
BPS	JESD22-B120	/	30 bonds/5 ea.	Pass
BS	JESD22-B116	/	30 bonds/5 ea.	Pass
SD	Steam aging, 245°C dipping	5s	22 leads*3 lot	Pass
	Package T	ype: SOIC16-WB	,	
Stress	Condition	Duration	Sample size	Results
PC	MSL 3	/	231*3 lot	Pass
HTSL	T <sub>A</sub> = 150°C	1000 hrs	77*3 lot	Pass



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HAST	130°C, 85% RH, 33.3psia, V <sub>cc1</sub> = 5.5V, V <sub>cc2</sub> = 5.5V	96 hrs	77*3 lot	Pass
TC	-65°C to 150°C	500 cycles	77*3 lot	Pass
UHAST	130°C, 85% RH, 33.3psia	96 hrs	77*3 lot	Pass
BPS	JESD22-B120	/	30 bonds/5 ea.	Pass
BS	JESD22-B116	/	30 bonds/5 ea.	Pass
SD	Steam aging, 245°C dipping	5s	22 leads*3 lot	Pass

#### Note:

- 1. 1 lot package reliability test data comes from qualification of CA-IS3722CHS, another 2 lot package reliability data refer to generic data of same package family.
- 2. 1 lot package reliability test data comes from qualification of CA-IS3052CG, another 2 lot package reliability data refer to generic data of same package family.
- 3. 1 lot package reliability test data comes from qualification of CA-IS3050CW, another 2 lot package reliability data refer to generic data of same package family.

## 6. Conclusion

CA-IS372XCX series chips are qualified according to JEDEC standards.



### **Disclaimer**

This information is provided to assist customers in design and development. It could change for technology innovation without notice.

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### **Revision History**

Revision	Change Log	Date
V1.0	Initial release	Jul, 2024
V1.1	Add information of package G and package W	Sep, 2024
V1.2	Add new part number of the same product family	Apr, 2025